2SB1424

Preliminary

PNP SILICON TRANSISTOR

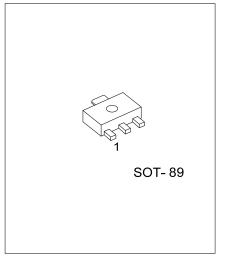
$\label{eq:low-vce(sat)} \ \ \textbf{TRANSISTOR}$

■ DESCRIPTION

As the UTC PNP silicon transistor, the **2SB1424** is the epitaxial planar type transistor which has very low $V_{\text{CE}(SAT)}$ (Collector-emitter saturation voltage).

■ FEATURES

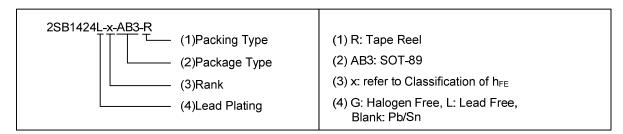
- * Very good DC current gain
- * Very low V_{CE(SAT)}=-0.2V@ I_C/I_B=(-2A)/(-0.1A)



Lead-free: 2SB1424L Halogen-free: 2SB1424G

■ ORDERING INFORMATION

Ordering Number			Dookogo	Pin Assignment			Dooking	
Normal	Lead Free	Halogen Free	Package	1	2	3	Packing	
2SB1424-x-AB3-R	2SB1424L-x-AB3-R	2SB1424G-x-AB3-R	SOT-89	В	С	Е	Tape Reel	



www.unisonic.com.tw 1 of 2

■ ABSOLUTE MAXIMUM RATING (T_a=25°C)

PARAMETER		SYMBOL	RATINGS	UNIT	
Collector-Base Voltage		V_{CBO}	-20	٧	
Collector-Emitter Voltage		V_{CEO}	-20	V	
Emitter-Base Voltage		V_{EBO}	-6	V	
Collector Current	DC	Ic	-3	А	
	Pulse(Note 2)	ic	-5		
Collector Dissipation		Pc	0.5	W	
Junction Temperature		T٦	150	$^{\circ}\mathbb{C}$	
Storage Temperature		T_{STG}	-55 ~ + 150	$^{\circ}\mathbb{C}$	

Note: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ **ELECTRICAL CHARACTERISTICS** (T_a=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	BV _{CBO}	I _C =-50μA , I _E =0	-20			V
Collector-Emitter Breakdown Voltage	BV _{CEO}	$I_C=-1mA$, $I_B=0$	-20			V
Emitter-Base Breakdown Voltage	BV_{EBO}	$I_E = -50 \mu A, I_C = 0$	-6			V
Collector Cutoff Current	I _{CBO}	V _{CB} =-20V			-0.1	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =-5V			-0.1	μΑ
ON CHARACTERISTICS						
DC Current Gain	h _{FE}	V _{CE} =-2V, I _C =-0.1A	120		390	
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	$I_{\rm C}/I_{\rm B} = (-2A)/(-0.1A)$			-0.5	V
SMALL-SIGNAL CHARACTERISTICS						
Current Gain Bandwidth Product	f⊤	V _{CE} =-2V, I _E =0.5A, f=100MHz		240		MHz
Output Capacitance	C _{ob}	V _{CB} =-10V, I _E =0, f=1MHz		35		pF

■ CLASSIFICATION OF h_{FF1}

RANK	Q	R
RANGE	120-270	180-390

UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.

^{2.} Pulse test: Pulse Width=10ms